

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit |
|--|---|------------------|--------------|------|
| Drain-Source Voltage | | V _{DSS} | 40 | V |
| Gate-Source Voltage | | V _{GSS} | ±20 | V |
| Continuous Drain Current, V _{GS} = 10V (Note 6) | T _A = +25°C T _A = +100°C | ID | 14.4 10.2 | А |
| Continuous Drain Current, V_{GS} = 10V (Note 7) | T _C = +25°C T _C = +100°C | ID | 64.8 45.8 | А |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | | IDM | 110 | А |
| Maximum Continuous Body Diode Forward Current (Note 7) | | ls | 55.5 | А |
| Avalanche Current, L = 0.1mH | | I _{AS} | 22.7 | А |
| Avalanche Energy, L = 0.1mH | | Eas | 25.7 | mJ |

Thermal Characteristics

| Characteristic | | Symbol | Value | Unit |
|--|----------------------|------------------|-------------|------|
| Total Power Dissipation (Note 6) | $T_A = +25^{\circ}C$ | PD | 2.99 | W |
| Thermal Resistance, Junction to Ambient (Note 6) | | R _{0JA} | 50.4 | °C/W |
| Total Power Dissipation (Note 7) | $T_C = +25^{\circ}C$ | PD | 55.5 | W |
| Thermal Resistance, Junction to Case (Note 7) | | R _{θJC} | 2.7 | °C/W |
| Operating and Storage Temperature Range | | TJ, TSTG | -55 to +175 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

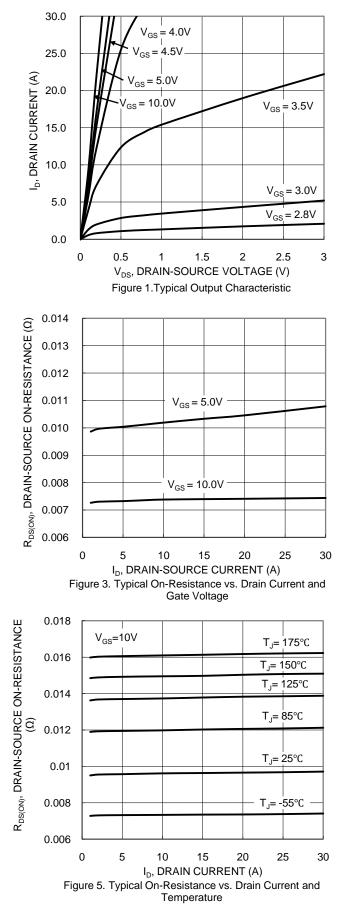
| Characteristic | Symbol | Min | Тур | Мах | Unit | Test Condition |
|--|---------------------|-------|------|-------|------|--|
| OFF CHARACTERISTICS (Note 8) | Symbol | WIIII | тур | IVIAA | Unit | Test condition |
| Drain-Source Breakdown Voltage | BV _{DSS} | 40 | _ | _ | V | $V_{GS} = 0V, I_D = 250 \mu A$ |
| Zero Gate Voltage Drain Current | IDSS | | _ | 1 | μA | $V_{DS} = 32V, V_{GS} = 0V$ |
| Gate-Source Leakage | I _{GSS} | | _ | ±100 | nA | $V_{\rm DS} = 02V, V_{\rm DS} = 0V$ $V_{\rm GS} = \pm 20V, V_{\rm DS} = 0V$ |
| ON CHARACTERISTICS (Note 8) | -033 | | | 2.00 | | 193 - 1101, 103 - 01 |
| Gate Threshold Voltage | V _{GS(TH)} | 1 | 1.6 | 3 | V | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ |
| | | _ | 7.3 | 8.8 | mΩ | $V_{GS} = 10V, I_D = 10A$ |
| Static Drain-Source On-Resistance | R _{DS(ON)} | _ | 10 | 13 | | $V_{GS} = 5V, I_D = 10A$ |
| Diode Forward Voltage | V _{SD} | _ | 0.8 | 1.0 | V | $V_{GS} = 0V, I_{S} = 10A$ |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | 1 | | |
| Input Capacitance | C _{iss} | | 1088 | | pF | $V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz |
| Output Capacitance | C _{oss} | _ | 322 | — | | |
| Reverse Transfer Capacitance | Crss | _ | 27 | _ | | |
| Gate Resistance | Rq | _ | 2.6 | | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | | 7.4 | | | V _{DS} = 20V, I _D = 10A |
| Total Gate Charge (V _{GS} = 10V) | Qg | _ | 15.3 | _ | | |
| Gate-Source Charge | Q _{gs} | _ | 2.4 | — | nC | |
| Gate-Drain Charge | Q _{gd} | _ | 3.4 | _ | | |
| Turn-On Delay Time | t _{D(ON)} | _ | 4.3 | — | | $V_{DD} = 20V, V_{GS} = 10V,$ $I_D = 10A, R_G = 6\Omega$ |
| Turn-On Rise Time | t _R | _ | 7.5 | | ns | |
| Turn-Off Delay Time | t _{D(OFF)} | | 16.7 | _ | | |
| Turn-Off Fall Time | t _F | — | 5.8 | — | 1 | |
| Body Diode Reverse Recovery Time | t _{RR} | | 20.2 | | ns | |
| Body Diode Reverse Recovery Charge | Q _{RR} | _ | 8.9 | _ | nC | I _F = 10A, di/dt = 100A/μs |

Notes: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

Device interview of a substance of solution, 200 point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.







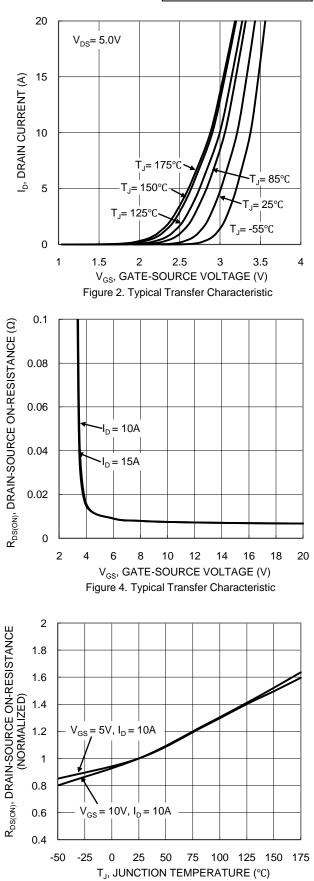
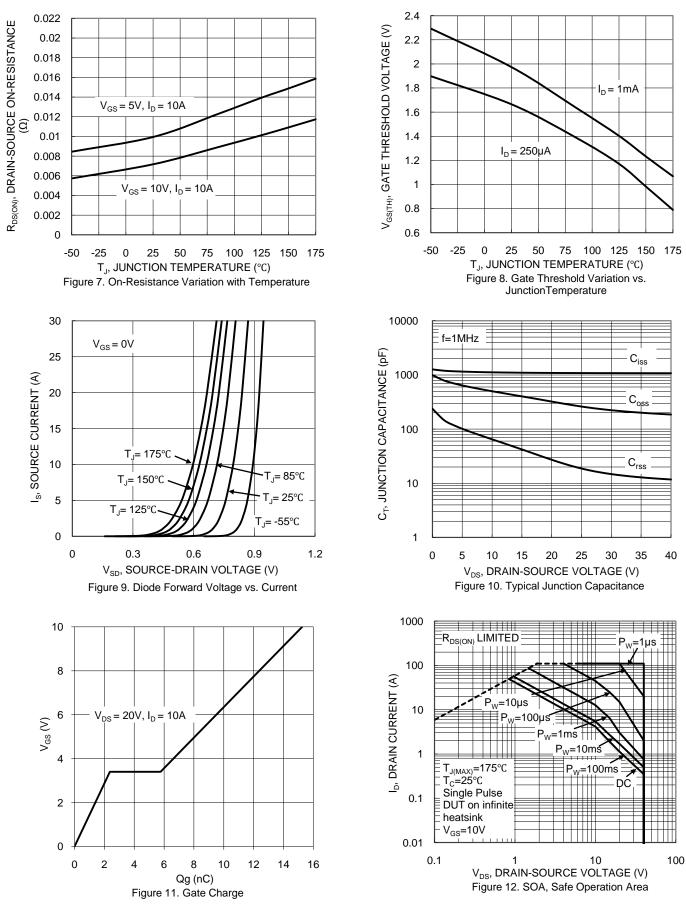


Figure 6. On-Resistance Variation with Temperature

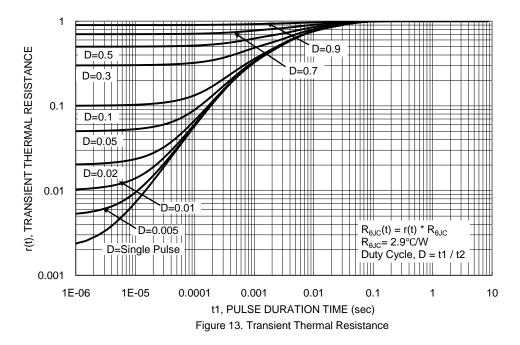


DMTH4008LPSQ



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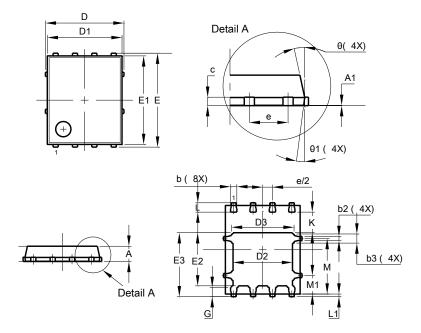




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

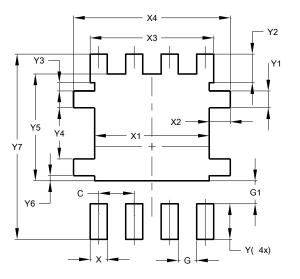


| PowerDI5060-8 | | | | | |
|---------------|----------------------|----------|-------|--|--|
| Dim | Min Max Typ | | | | |
| Α | 0.90 | 1.10 | 1.00 | | |
| A1 | 0.00 | 0.05 | - | | |
| b | 0.33 | 0.51 | 0.41 | | |
| b2 | 0.200 | 0.350 | 0.273 | | |
| b3 | 0.40 | 0.80 | 0.60 | | |
| С | 0.230 | 0.330 | 0.277 | | |
| D | 5.15 BSC | | | | |
| D1 | 4.70 | 5.10 | 4.90 | | |
| D2 | 3.70 | 4.10 | 3.90 | | |
| D3 | 3.90 | 4.30 | 4.10 | | |
| Е | | 6.15 BSC | ; | | |
| E1 | 5.60 | 6.00 | 5.80 | | |
| E2 | 3.28 | 3.68 | 3.48 | | |
| E3 | 3.99 | 4.39 | 4.19 | | |
| е | 1.27 BSC | | | | |
| G | 0.51 | 0.71 | 0.61 | | |
| K | 0.51 | - | - | | |
| L | 0.51 | 0.71 | 0.61 | | |
| L1 | 0.100 | 0.200 | 0.175 | | |
| М | 3.235 | 4.035 | 3.635 | | |
| M1 | 1.00 | 1.40 | 1.21 | | |
| Θ | 10° | 12° | 11° | | |
| Θ1 | 6° | 8° | 7° | | |
| Al | All Dimensions in mm | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



| Dimensions | Value (in mm) | | | |
|------------|---------------|--|--|--|
| С | 1.270 | | | |
| G | 0.660 | | | |
| G1 | 0.820 | | | |
| Х | 0.610 | | | |
| X1 | 4.100 | | | |
| X2 | 0.755 | | | |
| X3 | 4.420 | | | |
| X4 | 5.610 | | | |
| Y | 1.270 | | | |
| Y1 | 0.600 | | | |
| Y2 | 1.020 | | | |
| Y3 | 0.295 | | | |
| Y4 | 1.825 | | | |
| Y5 | 3.810 | | | |
| Y6 | 0.180 | | | |
| Y7 | 6.610 | | | |



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